

# Si-APD-Array SAH1L08-Series

## Description

The SAH1L08-Series is a linear Si-APD-array with 8 elements in a LCC44 package with protective window. Responsivity is optimised for 850 nm.



## Features

- 8 element APD array
- Very narrow gap
- High quantum efficiency
- Low noise, high speed
- 620 µm x 190 µm active area per element
- Wide operating temperature range
- Low crosstalk

## Applications

- Rangefinding
- LiDAR ACC
- Laser scanner

### Electro-Optical Characteristics, Ta= 25°C

| Parameter                          | Condition                                   | Min | Typ       | Max | Unit |
|------------------------------------|---|-----|-----------|-----|------|
| # of elements                      |   |     | 8         |     |      |
| Active area                        |   |     | 620 x 190 |     | µm   |
| Gap                                |   |     | 40        |     | µm   |
| Dark current I <sub>d</sub>        | M= 100, λ= 905 nm, per element              |     | 4         | 10  | nA   |
| Capacitance, C                     | M= 100, per element                         |     | 3         |     | pF   |
| Responsivity, R <sub>i</sub>       | M= 100, λ= 905 nm                           | 40  | 50        |     | A/W  |
| Rise time, t <sub>r</sub>          | M= 100, λ= 905 nm, R <sub>t</sub> = 50 Ohms |     | 1000      |     | psec |
| Breakdown voltage, V <sub>BR</sub> | I <sub>R</sub> = 10 µA                      | 80  | 150       | 200 | V    |
| Temperature coefficient            | I <sub>R</sub> = 10 µA                      |     | 0.44      |     | °K/V |
| Crosstalk                          | λ= 905 nm                                   |     | 50        |     | dB   |
| Dark current uniformity            | M= 100                                      |     | ±5        | ±20 | %    |
| Photo current uniformity           | M= 100, λ= 905 nm                           |     | ±5        | ±20 | %    |

### Absolute Maximum Ratings

| Parameter                   | Min      | Max   | Unit |
|-----------------------------|----------|-------|------|
| Storage temperature         | -55      | 100   |      |
| Operating temperature       | -40      | 85    | °C   |
| Soldering (15s)             |          | 260   |      |
| Reverse current (Peak)      | CW       | 0.200 |      |
|                             | 1s Pulse | 1     |      |
| Forward current (Avg)       | CW       | 10    | mA   |
|                             | 1s Pulse | 50    |      |
| Max total power dissipation |          | 60    | mW   |

**Curves**

Fig. 1: Spectral Response

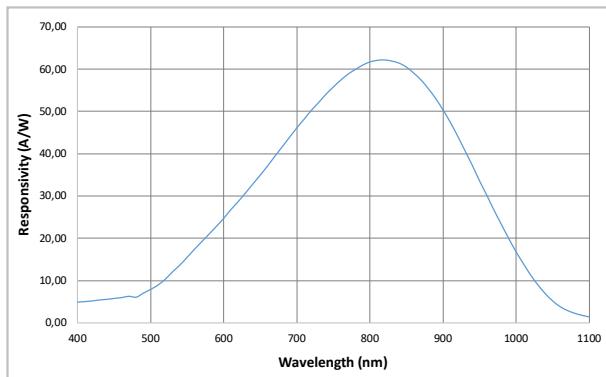


Fig. 2: Quantum Efficiency

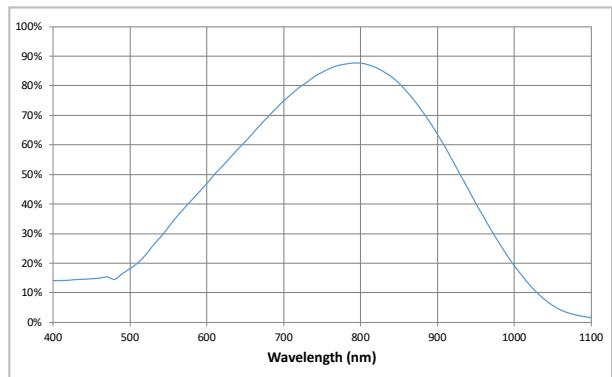


Fig. 3: Multiplication

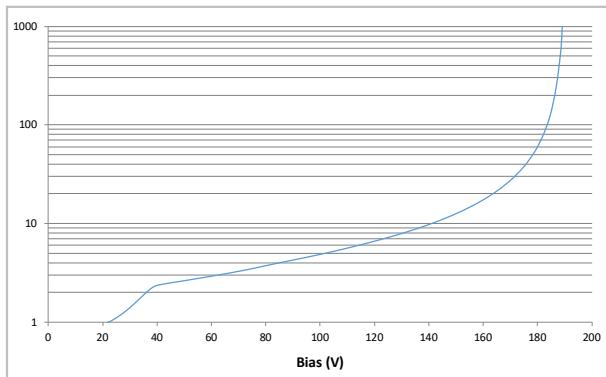


Fig. 4: Current vs. Reverse Voltage

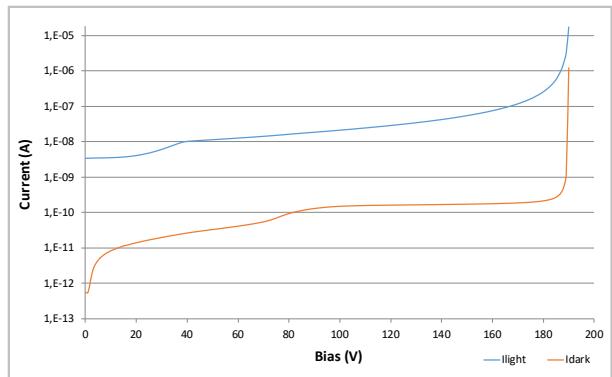


Fig. 5: Capacitance vs. Reverse Voltage

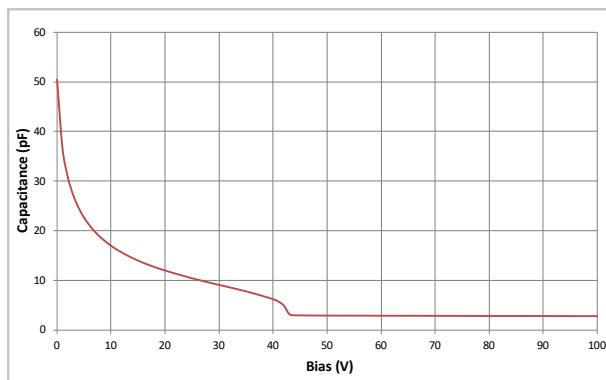
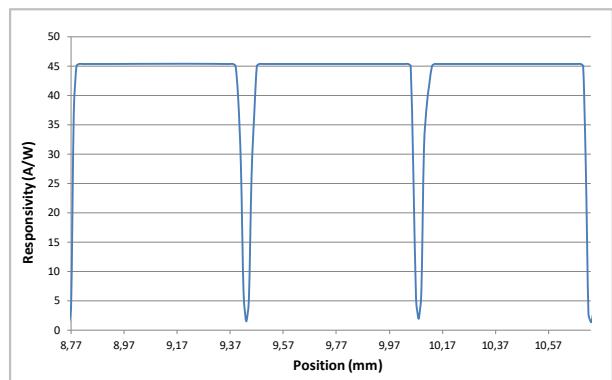
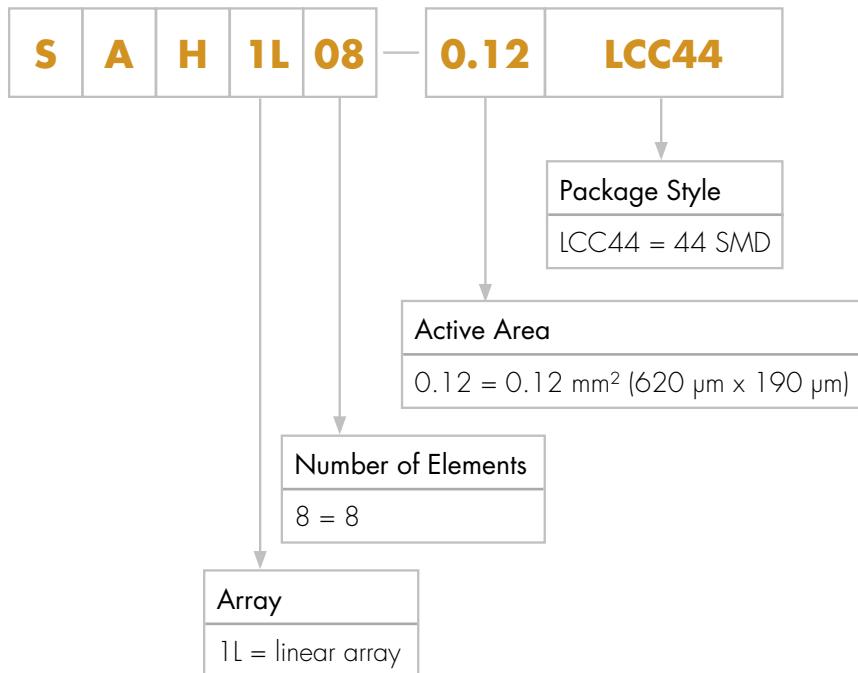


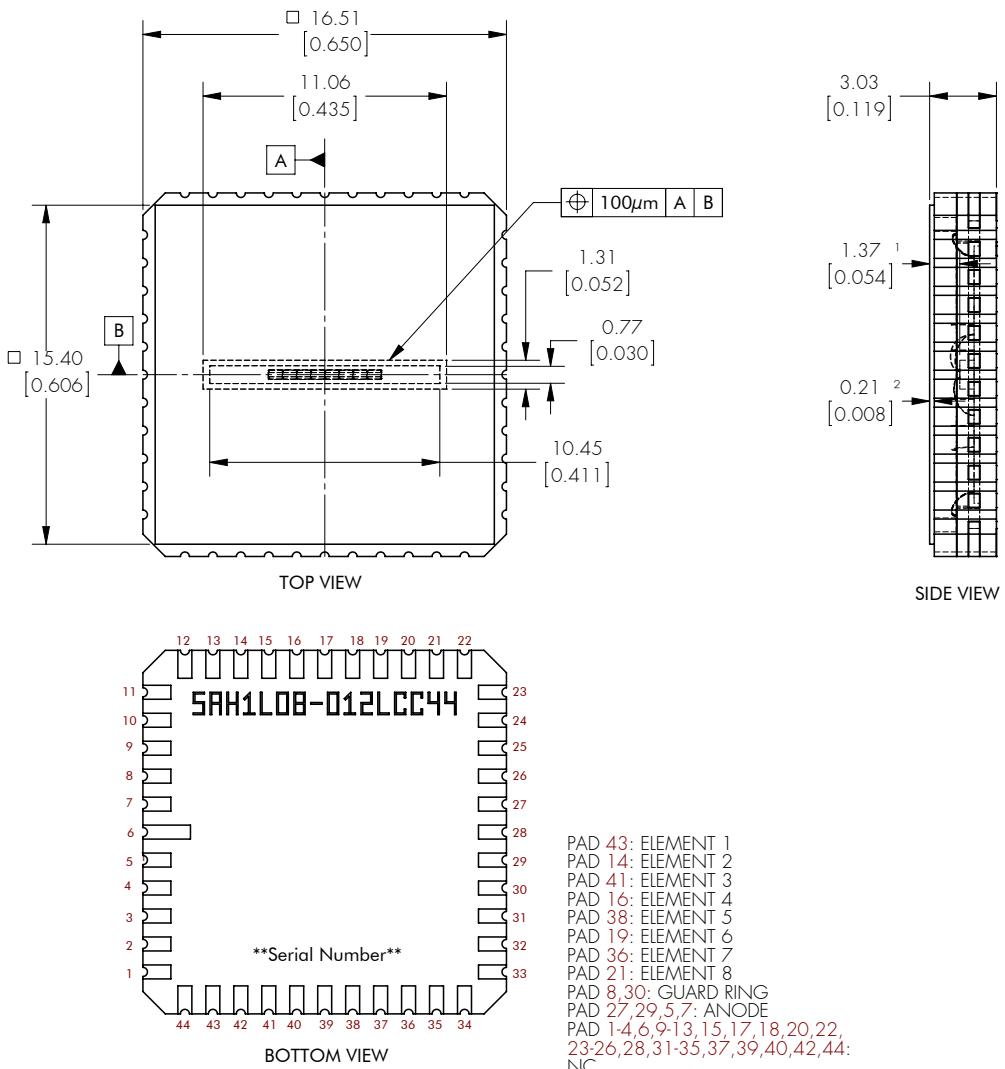
Fig. 6: Spot Scan



## Product Number Designation



## Package Drawings



## Product Changes

LASER COMPONENTS reserves the right to make changes to the product(s) or information contained herein without notice.

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## Ordering Information

Products can be ordered directly from LASER COMPONENTS or its representatives. For a complete listing of representatives, visit our website at [www.lasercomponents.com](http://www.lasercomponents.com)

Custom designed products are available on request.